

# MOS FIELD EFFECT TRANSISTOR

2SK1960

#### N-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

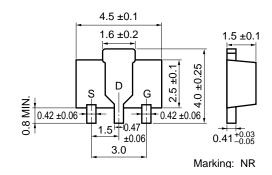
The 2SK1960 is an N-channel vertical MOS FET. Because it can be driven by a voltage as low as 1.5 V and it is not necessary to consider a drive current, this FET is ideal as an actuator for low-current portable systems such as headphone stereos and video cameras.

#### **FEATURES**

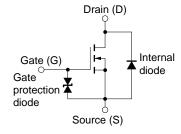
- · Gate can be driven by 1.5 V
- · Low ON resistance

 $R_{DS(on)} = 0.8 \Omega MAX$ . @ VGS = 1.5 V, ID = 0.1 A  $R_{DS(on)} = 0.2 \Omega MAX$ . @ VGS = 4.0 V, ID = 1.5 A

#### PACKAGE DIMENSIONS (in mm)



#### **EQUIVALENT CURCUIT**



#### PIN CONNECTIONS

S: Source

D: Drain G: Gate

#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS	RATING	UNIT
Drain to Source Voltage	VDSS	Ves = 0	16	V
Gate to Source Voltage	Vgss	Vps = 0	±7.0	V
Drain Current (DC)	I <sub>D(DC)</sub>		±3.0	А
Drain Current (Pulse)	D(pulse)	PW ≤ 10 ms, duty cycle ≤ 50 %	±6.0	А
Total Power Dissipation	Рт	$16 \text{ cm}^2 \times 0.7 \text{ mm}$ ceramic substrate used	2.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

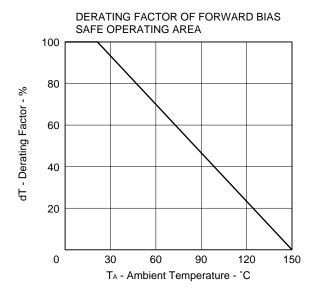


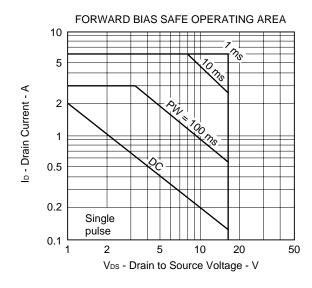
## ELECTRICAL CHARACTERISTICS (TA = 25 °C)

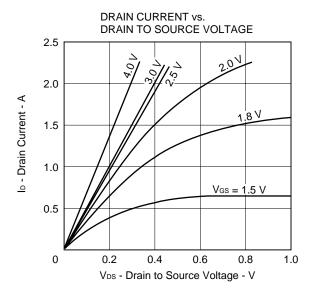
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-Off Current	Ipss	V <sub>DS</sub> = 16 V, V <sub>GS</sub> = 0			1.0	μΑ
Gate Leakage Current	Igss	$V_{GS} = \pm 7.0 \text{ V}, V_{DS} = 0$			±3.0	μΑ
Gate Cut-Off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 1 mA	0.5	0.8	1.1	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 1.5 A	2.0			S
Drain to Source On-State Resistance	RDS(on)1	Vgs = 1.5 V, ID = 0.1 A		0.35	0.8	Ω
Drain to Source On-State Resistance	RDS(on)2	Vgs = 2.5 V, ID = 1.5 A		0.17	0.3	Ω
Drain to Source On-State Resistance	RDS(on)3	Vgs = 4.0 V, ID = 1.5 A		0.12	0.2	Ω
Input Capacitance	Ciss	V <sub>DS</sub> = 3 V, V <sub>GS</sub> = 0, f = 1.0 MHz		370		pF
Output Capacitance	Coss			320		pF
Reverse Transfer Capacitance	Crss			115		pF
Turn-ON Delay Time	td(on)	VDD = 3 V, ID = 1.5 A, VGS(on) = 3 V,		70		ns
Rise Time	tr	$R_G = 10 \Omega$ , $R_L = 2 \Omega$		200		ns
Turn-OFF Delay Time	td(off)			150		ns
Fall Time	<b>t</b> f			200		ns

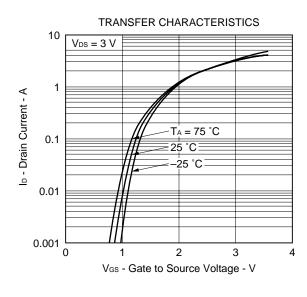
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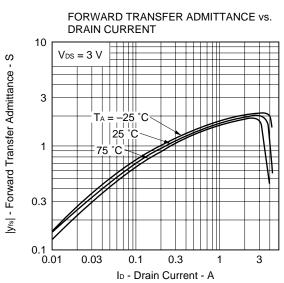
#### TYPICAL CHARACTERISTICS (TA = 25 °C)

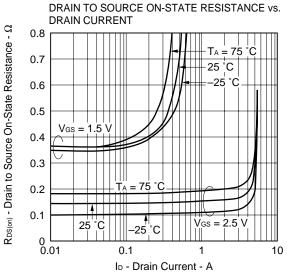




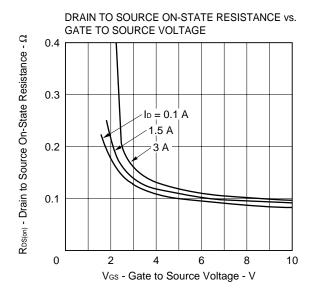


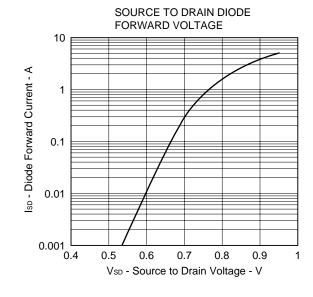


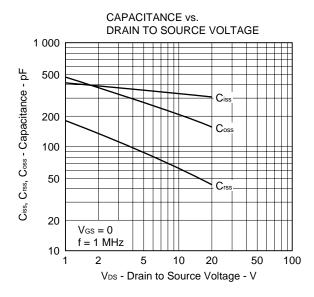


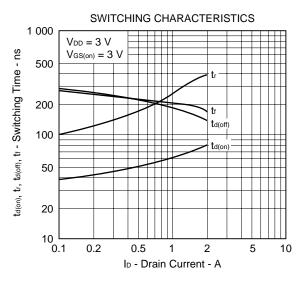














### REFERENCE

Document Name	Document No.		
NEC semiconductor device reliability/quality control system	TEI-1202		
Quality grade on NEC semiconductor devices	IEI-1209		
Semiconductor device mounting technology manual	C10535E		
Guide to quality assurance for semiconductor devices	MEI-1202		
Semiconductor selection guide	X10679E		

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